

FS70KM-2

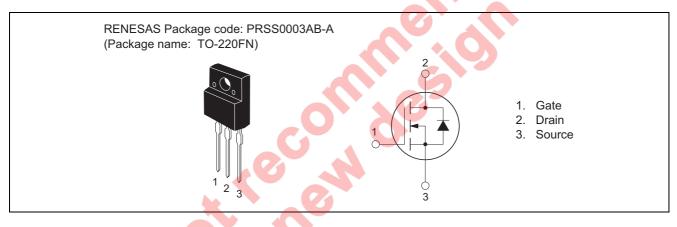
High-Speed Switching Use Nch Power MOS FET

REJ03G1428-0200 (Previous: MEJ02G0107-0101) Rev.2.00 Aug 07, 2006

Features

- Drive voltage : 10 V
- V_{DSS} : 100 V
- $r_{\text{DS(ON)}(\text{max})}$: 20 m Ω
- I_D: 70 A
- Integrated Fast Recovery Diode (TYP.): 120 ns
- Viso : 2000 V

Outline



Applications

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

Maximum Ratings

				$(\mathrm{Tc}=25^{\circ}\mathrm{C})$
Parameter	Symbol	Ratings	Unit	Conditions
Drain-source voltage	V _{DSS}	100	V	$V_{GS} = 0 V$
Gate-source voltage	V _{GSS}	±20	V	$V_{DS} = 0 V$
Drain current	I _D	70	A	
Drain current (Pulsed)	IDM	280	A	
Avalanche drain current (Pulsed)	I _{DA}	70	A	L = 100 μH
Source current	Is	70	A	
Source current (Pulsed)	I _{SM}	280	A	
Maximum power dissipation	PD	35	W	
Channel temperature	Tch	- 55 to +150	°C	
Storage temperature	Tstg	- 55 to +150	°C	
Isolation voltage	Viso	2000	V	AC for 1 minute,
				Terminal to case
Mass	_	2.0	g	Typical value



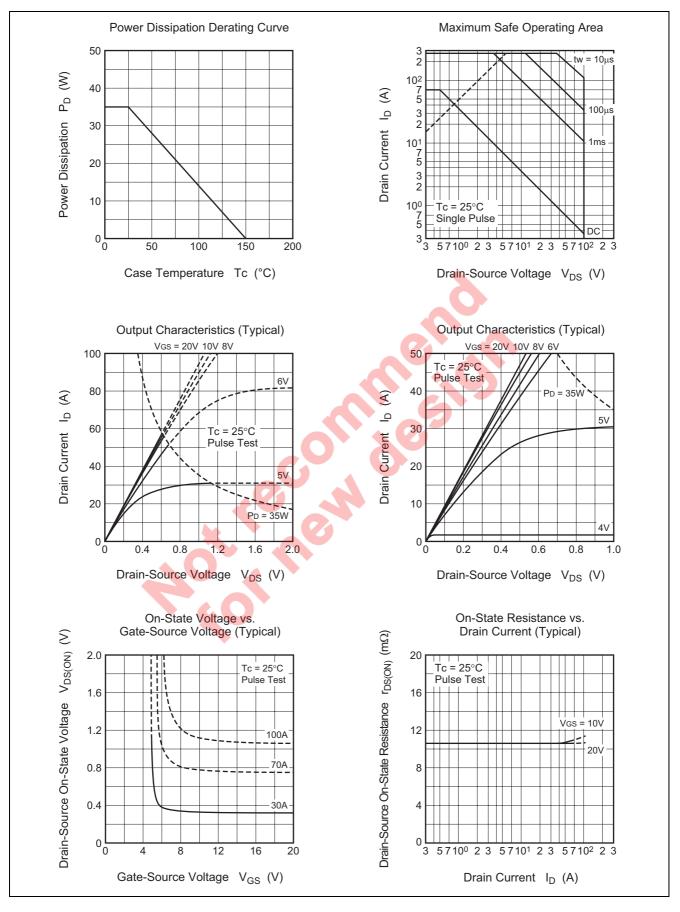
Electrical Characteristics

 $(Tch = 25^{\circ}C)$

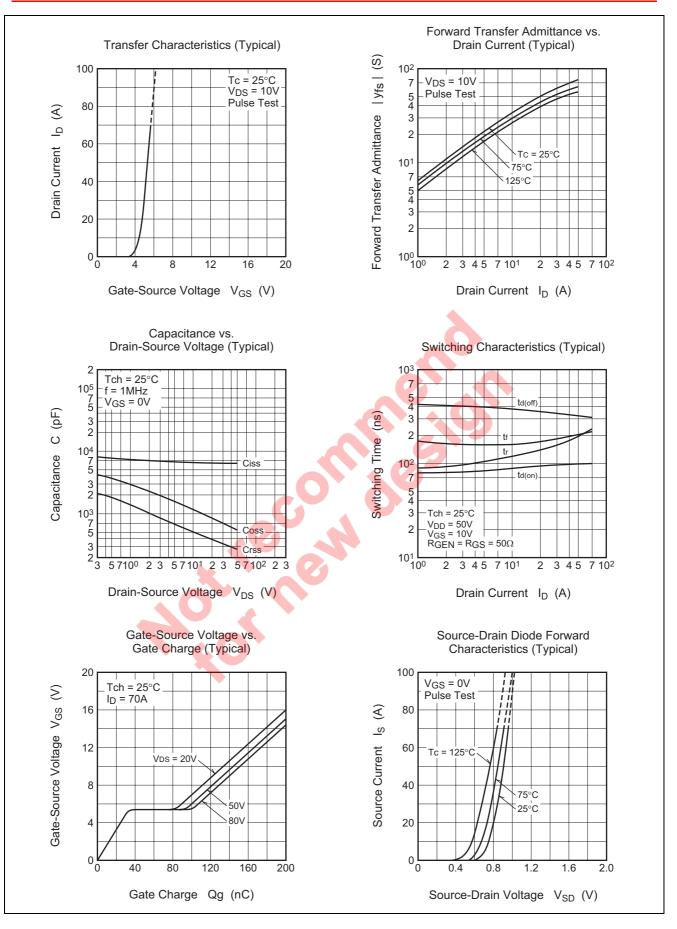
Parameter	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain-source breakdown voltage	V _{(BR)DSS}	100	—		V	$I_{D} = 1 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate-source leakage current	I _{GSS}		—	±0.1	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Drain-source leakage current	I _{DSS}	_	—	0.1	mA	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$
Gate-source threshold voltage	V _{GS(th)}	2.0	3.0	4.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Drain-source on-state resistance	r _{DS(ON)}	_	14	20	mΩ	$I_D = 35 \text{ A}, V_{GS} = 10 \text{ V}$
Drain-source on-state voltage	V _{DS(ON)}	_	0.49	0.7	V	$I_D = 35 \text{ A}, V_{GS} = 10 \text{ V}$
Forward transfer admittance	y _{fs}	_	53	—	S	$I_D = 35 \text{ A}, V_{DS} = 10 \text{ V}$
Input capacitance	Ciss	_	6540	—	рF	$V_{DS} = 10 V, V_{GS} = 0 V,$
Output capacitance	Coss	_	1150	—	рF	f = 1MHz
Reverse transfer capacitance	Crss	_	500	—	рF	
Turn-on delay time	t _{d(on)}	_	95	—	ns	$V_{DD} = 50 \text{ V}, \text{ I}_{D} = 35 \text{ A},$
Rise time	tr	_	175	—	ns	V _{GS} = 10 V,
Turn-off delay time	t _{d(off)}		330		ns	$R_{GEN} = R_{GS} = 50 \ \Omega$
Fall time	t _f		190		ns	
Source-drain voltage	V _{SD}	_	1.0	1.5	V	$I_{S} = 35 \text{ A}, V_{GS} = 0 \text{ V}$
Thermal resistance	R _{th(ch-c)}	_	_	3.57	°C/W	Channel to case
Reverse recovery time	t _{rr}	_	120		ns	$I_{S} = 70 \text{ A}, d_{is}/d_{t} = -100 \text{ A}/\mu \text{s}$

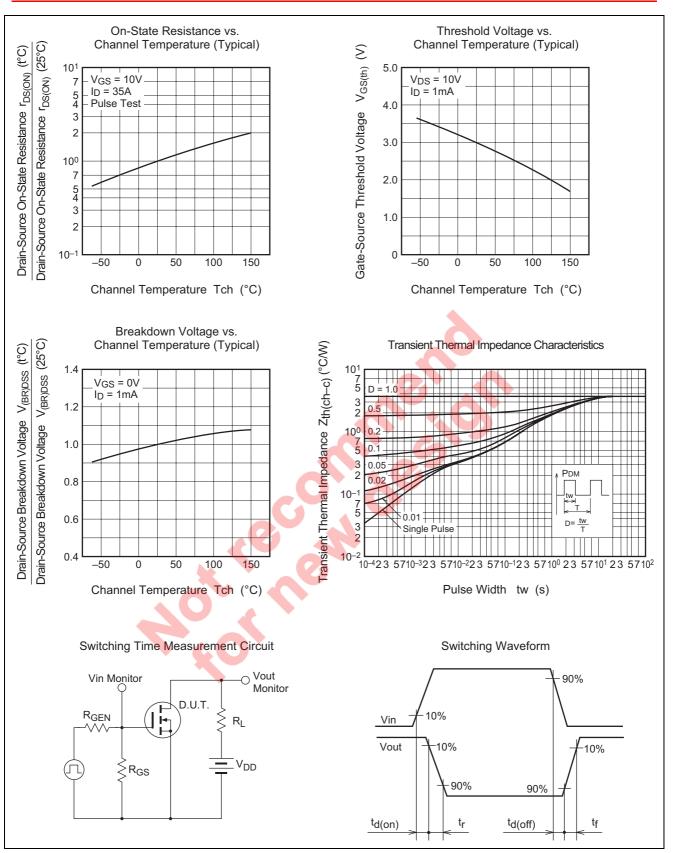


Performance Curves

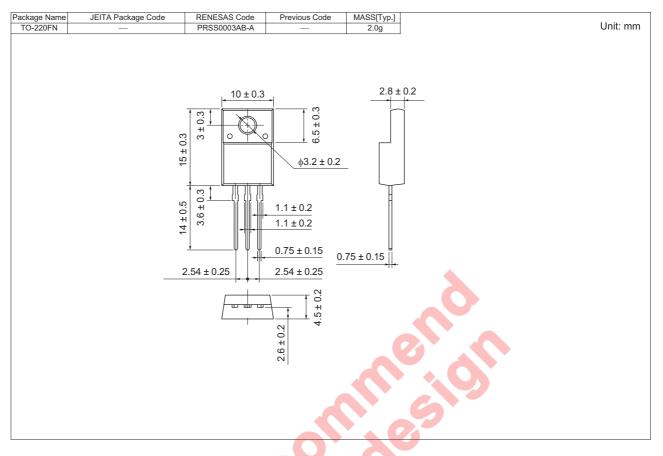








Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50	Type name	FS70KM-2
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	FS70KM-2-A8

Note : Please confirm the specification about the shipping in detail.

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